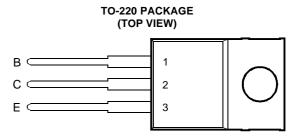
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- Designed for Complementary Use with TIP120, TIP121 and TIP122
- 65 W at 25°C Case Temperature
- 5 A Continuous Collector Current
- Minimum h<sub>FE</sub> of 1000 at 3 V, 3 A



Pin 2 is in electrical contact with the mounting base.

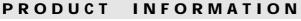
MDTRACA

#### absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING			VALUE	UNIT	
	TIP125		-60		
Collector-base voltage $(I_E = 0)$	TIP126	V <sub>CBO</sub>	-80	V	
	TIP127		-100		
	TIP125		-60		
Collector-emitter voltage ( $I_B = 0$ )	TIP126	V <sub>CEO</sub>	-80	V	
	TIP127		-100		
Emitter-base voltage			-5	V	
Continuous collector current			-5	A	
Peak collector current (see Note 1)			-8	A	
Continuous base current			-0.1	A	
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)			65	W	
Continuous device dissipation at (or below) 25°C free air temperature (see Note 3)			2	W	
Unclamped inductive load energy (see Note 4)			50	mJ	
Operating junction temperature range			-65 to +150	°C	
Storage temperature range			-65 to +150	°C	
Lead temperature 3.2 mm from case for 10 seconds			260	°C	

NOTES: 1. This value applies for  $t_p \leq 0.3$  ms, duty cycle  $\leq 10\%.$ 

- 2. Derate linearly to 150°C case temperature at the rate of 0.52 W/°C.
- 3. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.
- 4. This rating is based on the capability of the transistor to operate safely in a circuit of: L = 20 mH,  $I_{B(on)}$  = -5 mA,  $R_{BE}$  = 100  $\Omega$ ,  $V_{BE(off)}$  = 0,  $R_S$  = 0.1  $\Omega$ ,  $V_{CC}$  = -20 V.





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### electrical characteristics at 25°C case temperature

PARAMETER			TEST CONDITION	ONS	MIN	TYP	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-emitter breakdown voltage	$I_{\rm C} = -30 \mathrm{mA}$	I <sub>B</sub> = 0	TIP125 TIP126	-60 -80			V
I <sub>CEO</sub>	Collector-emitter cut-off current	(see Note 5) $V_{CE} = -30 V$ $V_{CE} = -40 V$ $V_{CE} = -50 V$	$I_{B} = 0$ $I_{B} = 0$ $I_{B} = 0$	TIP127 TIP125 TIP126 TIP127	-100		-0.5 -0.5 -0.5	mA
I <sub>CBO</sub>	Collector cut-off current	$V_{CB} = -60 V$ $V_{CB} = -80 V$ $V_{CB} = -100 V$	$I_{E} = 0$ $I_{E} = 0$ $I_{E} = 0$	TIP125 TIP126 TIP127			-0.2 -0.2 -0.2	mA
I <sub>EBO</sub>	Emitter cut-off current	V <sub>EB</sub> = -5 V	I <sub>C</sub> = 0				-2	mA
h <sub>FE</sub>	Forward current transfer ratio	$V_{CE} = -3 V$ $V_{CE} = -3 V$	$I_{\rm C} = -0.5 \text{ A}$ $I_{\rm C} = -3 \text{ A}$	(see Notes 5 and 6)	1000 1000			
V <sub>CE(sat)</sub>	Collector-emitter saturation voltage	$I_B = -12 \text{ mA}$ $I_B = -20 \text{ mA}$	I <sub>C</sub> =    -3 A I <sub>C</sub> =    -5 A	(see Notes 5 and 6)			-2 -4	V
$V_{BE}$	Base-emitter voltage	V <sub>CE</sub> = -3 V	I <sub>C</sub> = -3 A	(see Notes 5 and 6)			-2.5	V
$V_{EC}$	Parallel diode forward voltage	I <sub>E</sub> = -5 A	I <sub>B</sub> = 0	(see Notes 5 and 6)			-3.5	V

NOTES: 5. These parameters must be measured using pulse techniques,  $t_p$  = 300  $\mu s,$  duty cycle  $\leq$  2%.

6. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

### thermal characteristics

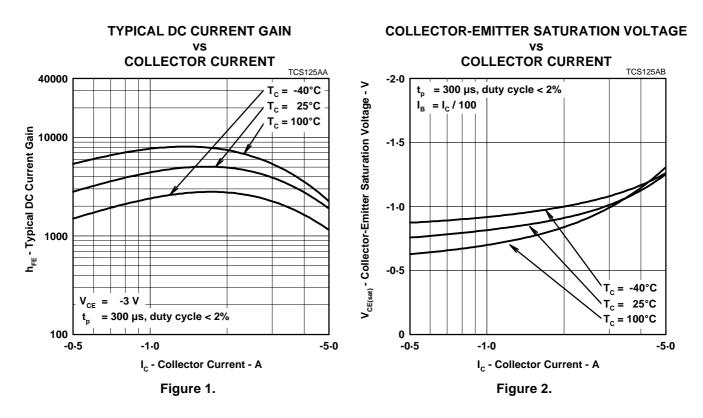
PARAMETER			ТҮР	MAX	UNIT
$R_{\theta JC}$	Junction to case thermal resistance			1.92	°C/W
$R_{\thetaJA}$	Junction to free air thermal resistance			62.5	°C/W

### resistive-load-switching characteristics at 25°C case temperature

PARAMETER	TEST CONDITIONS <sup>†</sup>			MIN	ТҮР	MAX	UNIT
t <sub>on</sub> Turn-on time	I <sub>C</sub> = -3 A	I <sub>B(on)</sub> = -12 mA	I <sub>B(off)</sub> = 12 mA		1.5		μs
t <sub>off</sub> Turn-off time	V <sub>BE(off)</sub> = 5 V	$R_L = 10 \ \Omega$	$t_p$ = 20 µs, dc $\leq$ 2%		8.5		μs

<sup>†</sup> Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

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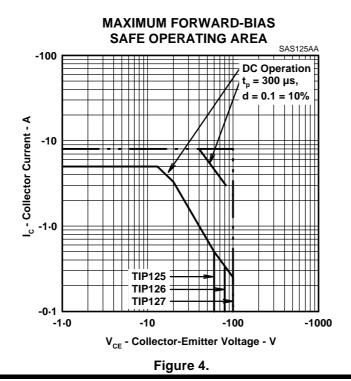
### **TYPICAL CHARACTERISTICS**

**BASE-EMITTER SATURATION VOLTAGE** vs **COLLECTOR CURRENT** TCS125AC -3-0  $T_c = -40^{\circ}C$ V<sub>BE(sat)</sub> - Base-Emitter Saturation Voltage - V 25°C T<sub>c</sub> = T<sub>c</sub> = 100°C -2-0 -2-5 -1-0 -1-5  $I_{\rm B} = I_{\rm C} / 100$ = 300 µs, duty cycle < 2% t, -0-5 -0-5 -1-0 -5-0 I<sub>c</sub> - Collector Current - A



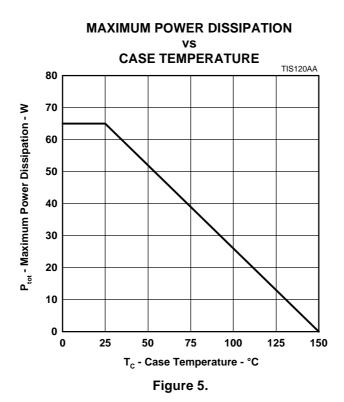


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#### MAXIMUM SAFE OPERATING REGIONS





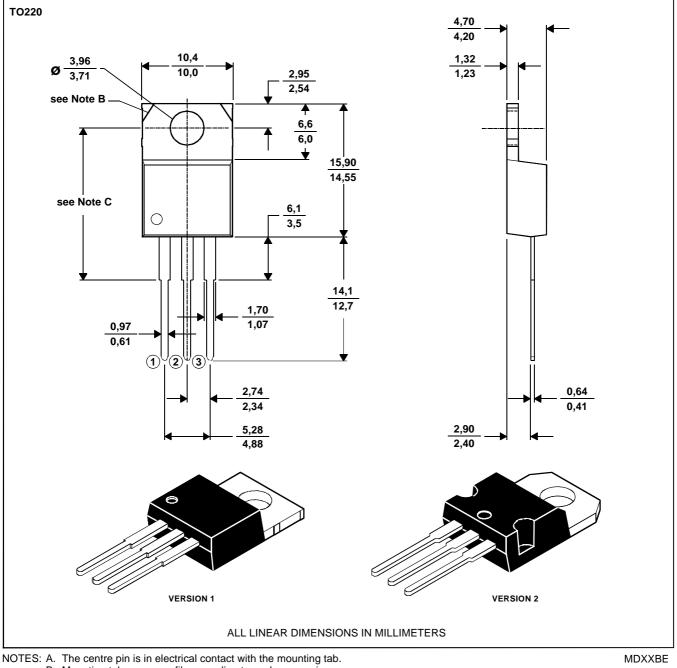
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## **MECHANICAL DATA**

## TO-220

### 3-pin plastic flange-mount package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



B. Mounting tab corner profile according to package version.

C. Typical fixing hole centre stand off height according to package version.

Version 1, 18.0 mm. Version 2, 17.6 mm.

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